

Department of ECE, Bennett University

EECE105L: Fundamentals of Electrical and Electronics Engineering

Tutorial Sheet-13

Topics Covered: Diode Circuits

If not mentioned, assume non-ideality factor ( $\eta$ ) as 1.5, reverse saturation current  $I_0$  as 5 nA.

1. A PN junction diode is in series with a  $100\text{ k}\Omega$  resistor and 3.5 V supply. If the diode is forward biased, determine the current through the diode and voltage across the diode. Given that the reverse saturation current is 5 nA and built-in voltage of diode is 0.6 V.
2. For the diode circuit shown in Fig. 1,  $V_S = 2\text{ V}$ . The silicon diode has a reverse saturation current of 1 nA at 300 K. Given that  $V = 0.7\text{ V}$ . Find
  - i)  $R_2$  when  $R_1 = 1\text{ k}\Omega$  and ii)  $R_1$  when  $R_2 = 1\text{ k}\Omega$

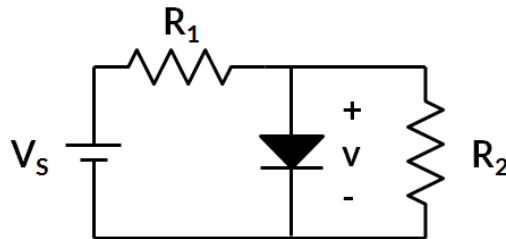


Fig. 1

3. For the diode circuit shown in Fig. 2,  $V_S = 6\text{ V}$  and have a reverse saturation current of 1 nA at 300 K. Answer the following questions:
  - i) Find  $R_2$  when  $R_1 = 10\text{ k}\Omega$  and  $V_1 = 0.66\text{ V}$
  - ii) Find  $R_1$  when  $R_2 = 100\text{ }\Omega$  and  $V_2 = 0.66\text{ V}$
  - iii) Find  $R_1$  and  $R_2$  when  $V_1 = 0.68\text{ V}$  and  $V_2 = 0.66\text{ V}$ .

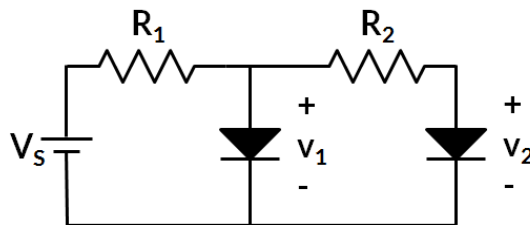


Fig. 2

4. For the diode circuit shown in Fig. 3  $D_1$  and  $D_2$  are silicon diodes having saturation currents of 5 nA and 10 nA respectively, at 300 K. Given that both the diodes are forward biased. Find the values of R for which the current is 15 mA.

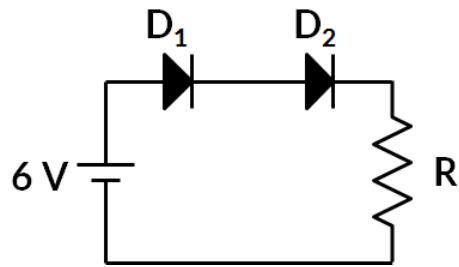


Fig. 3

5. For the ideal diode circuit shown in Fig. 4, let  $R_f = 1\text{ k}\Omega$  and  $R = 9\text{ k}\Omega$ . Find the output voltage  $V_o$  when,
- $V_1 = V_2 = 0\text{ V}$
  - $V_1 = 10\text{ V}, V_2 = 0\text{ V}$
  - $V_1 = V_2 = 10\text{ V}$

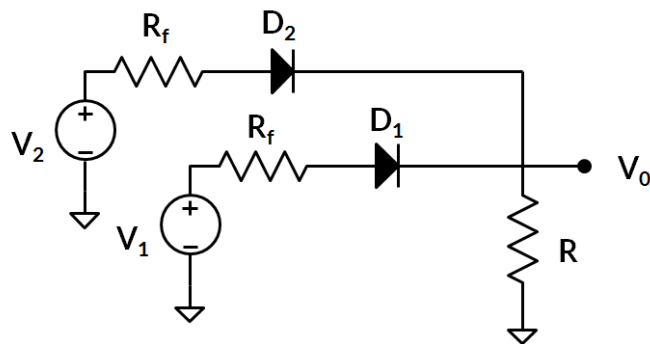


Fig. 4

6. Consider the circuit shown in fig. 5. Determine the current through diode and voltage across the diode. Assume that the cut-in voltage of diode is  $0.6\text{ V}$ .

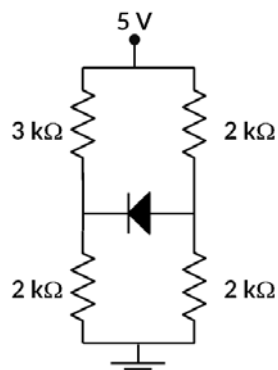


Fig. 5

7. The reverse saturation current of each diode in fig. 6 is  $2 \times 10^{-10}\text{ A}$ . Determine the input voltage required to produce an output voltage of  $0.60\text{ V}$ .

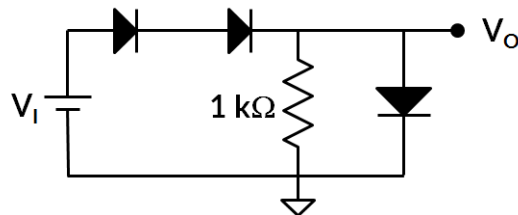


Fig. 6

8. Assume that each diode in circuit shown in fig. 7 has a cut-in voltage of 0.65 V.

i) If the input voltage is  $V_I = 5V$ , determine the value of  $R_1$  such that  $I_{D1}$  is one-half of  $I_{D2}$ . What are the values of  $I_{D1}$  and  $I_{D2}$ ?

ii) If  $V_I = 8V$  and  $R_1 = 2 k\Omega$ , determine  $I_{D1}$  and  $I_{D2}$ .

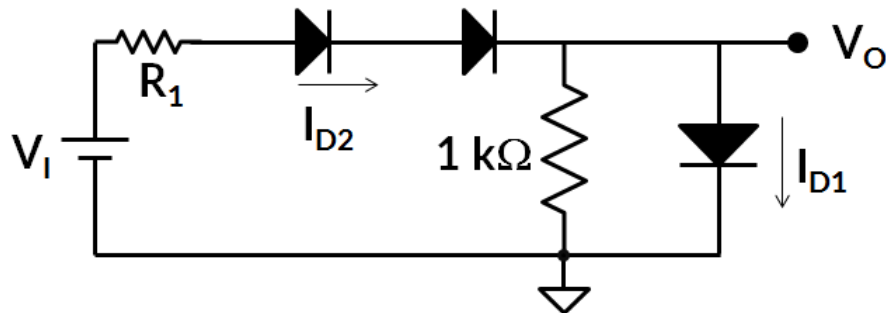


Fig. 7

9. In the circuit shown in fig. 8, find the diode voltage  $V_D$  and the supply voltage  $V$  such that the current  $I_D = 0.4$  mA. Assume cut-in voltage is 0.7V. What is the power dissipated by the diode?

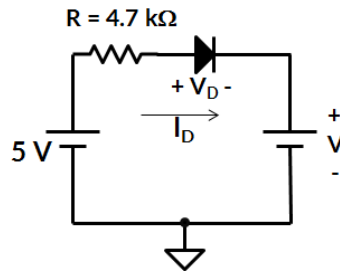


Fig. 8

----- END OF QUESTIONS -----

Answers:

- 1)  $V_D = 0.6 V$ ,  $I_D = 29 \mu A$
- 2) i)  $R_2 = 538 \Omega$ , ii)  $R_1 = 1.68 k\Omega$
- 3) i)  $R_2 = 110 \Omega$ , ii)  $R_1 = 8.82 k\Omega$  iii)  $R_1 = 62 \Omega$ ,  $R_2 = 11 k\Omega$
- 4)  $R = 350 \Omega$
- 5) i)  $V_O = 0 V$  ii)  $V_O = 8.46 V$  iii)  $V_O = 8.91 V$

- 6)  $I_D = 0 \text{ A}$ ,  $V_D = -0.5 \text{ V}$
- 7)  $V_I = 1.378 \text{ V}$
- 8) i)  $I_{D1} = 0.65 \text{ mA}$ ,  $I_{D2} = 1.3 \text{ mA}$ ,  $R_1 = 2.35 \text{ k}\Omega$  i)  $I_{D1} = 2.375 \text{ mA}$ ,  $I_{D2} = 3.025 \text{ mA}$
- 9)  $V = 2.42 \text{ V}$ ,  $P = 0.28 \text{ mW}$